Vishay Semiconductors

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VS-20CTH03-M3

| PRIMARY CHARACTERISTICS | | | | | | |
|----------------------------------|--------------------|--|--|--|--|--|
| I _{F(AV)} 2 x 10 A | | | | | | |
| V _R | 300 V | | | | | |
| V _F at I _F | 0.85 V | | | | | |
| t _{rr} typ. | See Recovery table | | | | | |
| T _J max. | 175 °C | | | | | |
| Package | 3L TO-220AB | | | | | |
| Circuit configuration | Common cathode | | | | | |

FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

300 V series are the state of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | | |
|--|-----------------------------------|------------------|-------------------------|--------|-------|--|--|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | | |
| Peak repetitive reverse voltage | V _{RRM} | | 300 | V | | | | | |
| Average rectified forward current | per diode | levve. | T _C = 160 °C | 10 | | | | | |
| Average rectilied forward current | per device | IF(AV) | | 20 | А | | | | |
| Non-repetitive peak surge current | | I _{FSM} | T _J = 25 °C | 120 | | | | | |
| Operating junction and storage tempera | T _J , T _{Stg} | | -65 to +175 | °C | | | | | |

| ELECTRICAL SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified) | | | | | | | | |
|---|-------------------------------------|---|------|------|------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I _R = 100 μA | 300 | - | - | | | |
| | V _F | I _F = 10 A | - | 1.05 | 1.25 | V | | |
| Forward voltage | | I _F = 10 A, T _J = 125 °C | - | 0.85 | 0.95 | | | |
| Povoroo lookogo ourropt | | $V_{R} = V_{R}$ rated | - | - | 20 | | | |
| Reverse leakage current | I _R | $T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$ | - | 6 | 200 | μA | | |
| Junction capacitance | CT | V _R = 300 V | - | 30 | - | pF | | |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8 | - | nH | | |

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 1
 Document Number: 96205

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| DYNAMIC RECOVERY CHARACTERISTICS ($T_C = 25$ °C unless otherwise specified) | | | | | | | | | |
|---|------------------|--|---|------|------|------|-------|--|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS | | |
| | | $I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}$ | õs, V _R = 30 V | - | - | 35 | | | |
| Poverse recevery time | + | $I_F = 1 \text{ A}, \ dI_F/dt = 100$ | - | - | 30 | ns | | | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 31 | - | 115 | | |
| | | T _J = 125 °C | $\begin{array}{l} I_F = 10 \text{ A} \\ dI_F/dt = 200 \text{ A}/\mu\text{s} \\ V_R = 200 \text{ V} \end{array}$ | - | 42 | - | | | |
| Deals receivers ourrent | I _{RRM} | T _J = 25 °C | | - | 2.4 | - | А | | |
| Peak recovery current | | T _J = 125 °C | | - | 5.6 | - | A | | |
| Reverse recovery charge | 0 | T _J = 25 °C | | - | 36 | - | nC | | |
| | Q _{rr} | T _J = 125 °C | | - | 120 | - | 10 | | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | | |
|---|-----------------------------------|---|---------|------|------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -65 | - | 175 | °C | | | |
| Thermal resistance, junction-to-case per diode | R _{thJC} | Mounting surface, flat, smooth, and greased | - | - | 1.5 | °C/W | | | |
| Marking device | | Case style 3L TO-220AB | 20CTH03 | | | | | | |

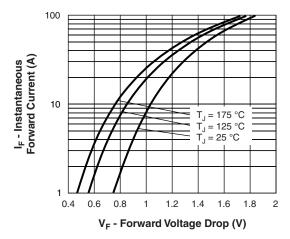


Fig. 1 - Typical Forward Voltage Drop Characteristics

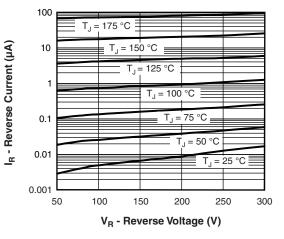


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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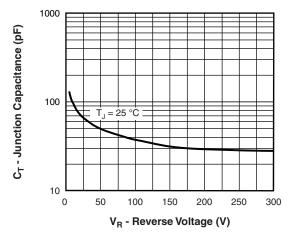


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

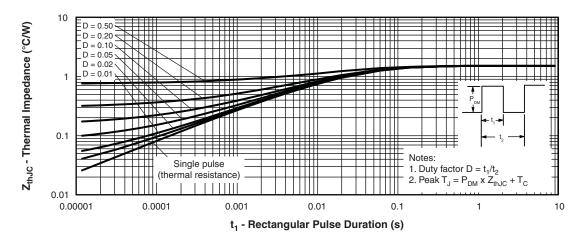
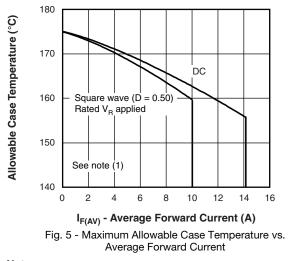
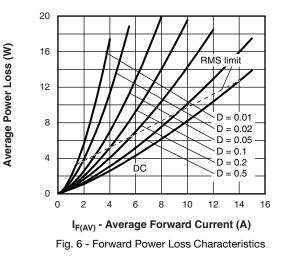


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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= 10 A

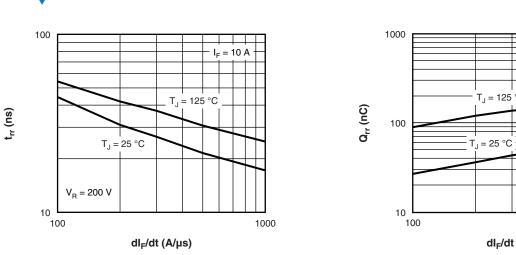


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

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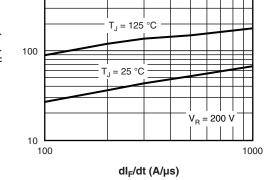


Fig. 8 - Typical Stored Charge vs. dl_F/dt

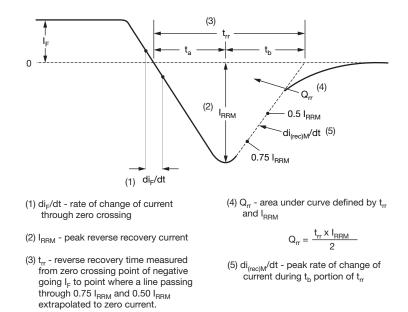


Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

| Device code | VS- | 20 | С | т | н | 03 | -M3 |
|-------------|-----|----------------|-----------|----------------------|-----------|---------|----------------|
| | | | | | | | |
| | 1 | 2 | 3 | 4 | 5 | 6 | $\overline{7}$ |
| | | \ <i>/</i> :-1 | 0 | | | 1 1 | |
| | | - Visr | nay Sem | liconduc | ctors pro | Jauct | |
| | 2 | - Cur | rent rati | ng (20 = | : 20 A) | | |
| | 3 | - C = | commo | on catho | de | | |
| | 4 | - T= | TO-220 | , D ² PAk | K (TO-26 | 63AB) | |
| | 5 | - H= | hyperfa | st recov | /ery | | |
| | 6 | - Volt | age rati | ng (03 = | = 300 V) | | |
| | 7 | - Env | ironmer | ntal digit | : | | |
| | | -M3 | s = halog | gen-free | , RoHS | -compli | ant, and |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-20CTH03-M3 | 50 | 1000 | Antistatic plastic tube | | | | |

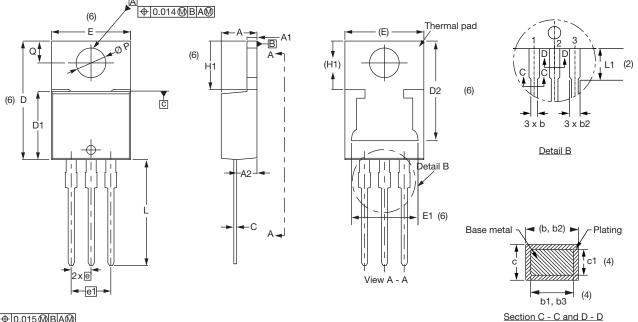
| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions | www.vishay.com/doc?96154 | | | | |
| Part marking information | www.vishay.com/doc?95028 | | | | |
| SPICE model | www.vishay.com/doc?96583 | | | | |



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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕0.015**0**BA0





| SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|---------|--------|--------|-------|-------|-------|
| STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.25 | 4.65 | 0.167 | 0.183 | |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | |
| A2 | 2.50 | 2.92 | 0.098 | 0.115 | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| с | 0.36 | 0.61 | 0.014 | 0.024 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 |
| D | 14.85 | 15.35 | 0.585 | 0.604 | 3 |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | |

| SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|--------|--------|--------|-------|-------|-------|
| STWDUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D2 | 11.68 | 13.30 | 0.460 | 0.524 | 6, 7 |
| Ш | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |
| E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| е | 2.41 | 2.67 | 0.095 | 0.105 | |
| e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6 |
| L | 13.52 | 14.02 | 0.532 | 0.552 | |
| L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| ØР | 3.54 | 3.91 | 0.139 | 0.154 | |
| Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| | | | | | |

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1

⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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